Open Archive Toulouse Archive Ouverte (OATAO)
OATAO is an open access repository that collects the work of Toulouse researchers and makes it freely available over the web where possible.

This is an author-deposited version published in: http://oatao.univ-toulouse.fr/
Eprints ID: 8614

To link to this article: DOI: 10.1016/j.electacta.2011.03.099
URL: http://dx.doi.org/10.1016/j.electacta.2011.03.099

To cite this version:

Any correspondence concerning this service should be sent to the repository administrator: staff-oatao@listes.diff.inp-toulouse.fr
Fluoroacidity evaluation in molten salts

A.L. Bieber, L. Massot*, M. Gibilaro, L. Cassayre, P. Chamelot, P. Taxil

Laboratoire de Génie Chimique UMR 5503, Département Procédés Electrochimiques, Université de Toulouse, 31062 Toulouse Cedex, France

ABSTRACT

The fluoroacidity of several alkaline fluoride media was studied by monitoring the concentration of electroactive species which is decreasing vs. time due to a gas species release, such as silicon fluorides, as indicated by the reaction: SiF$_4$ + e$^-$ → SiF$_4$(g) + e$^-$. This article relates the Si(IV) reaction study to define a relative fluoroacidity scale by studying the silicon ions stability in different melts. Electrochemical techniques allow the measurement of SiF$_4$ + e$^-$. The reaction rate constant to be calculated at different temperatures and for several fluoride media. The article shows that the free F$^-$ content depends on the fluoride mixture and that the rate values are correlated with the fluoroacidity allowing a qualitative estimation. Then a fluoroacids fluoroacidity scale was proposed, scaling the different eutectic melts from basic melt to acidic one: NaF–Kf < LiF–KF < NaF–MgF$_2$ < NaF–CaF$_2$ < LiF–NaF < LiF–CaF$_2$. The fluoroacidity of a molten salt containing fluoride ions is defined by the free F$^-$ content in a bath defined by:

$$\text{pF}_{\text{aq}} = -\log a_{\text{F}^-}$$

where $a_{\text{F}^-}$ is the activity of free F$^-$ ions in the mixture.

The pF$^-$ role is similar to the pH for protic solvent, hence it is a key parameter in molten fluorides for applications such as electrodissolution. The fluoroacidity influences the solute ions coordination in the medium and thus the physico-chemical properties of the molten solutions. For the expression of the acid–base equilibrium of the fluoride solution, a similar concept early developed in chloroacidity media was used and reported in [1] and assessing the following equilibrium:

$$\text{chlorobase} = \text{chloroacid} + n\text{Cl}^-$$

$$\text{fluorobase} = \text{fluoracid} + n\text{F}^-$$

The main difficulty for constructing thermodynamic diagrams (e.g. Pourbaix diagram for aqueous solution) in fluoride media is the lack of thermodynamic data, due to the unavailability of a stable reference electrode [2], explaining why only very few fluoroacidity studies in molten fluorides have been dedicated to this concept, except those performed in cryolite media (Na$_3$AlF$_6$), used as electrolyte for aluminum production [3]. A key parameter is the acidity of the bath, which refers to the AlF$_3$ concentration. Dewing [4] defined a coefficient describing the acid/base character of a given component in the cryolite mixture. Many additives were sorted from weak base to strong acid: BaF$_2$ < SrF$_2$ < LiF < CaF$_2$ < BeF$_2$ < MgF$_2$ [4–6].

Fluoroacidity has to be studied for a better knowledge of the melt acidic properties modifying the physico-chemical properties of a solute. In the case of silicon ions in molten fluorides, Elwell [7] studied the Si(IV) volatility difference in BaF$_2$, CaF$_2$, MgF$_2$ and NaF or KF mixtures concluding that Si(IV) is better stabilized in NaF–BaF$_2$. Nohira [8] demonstrated that LiCl–KCl–LiF silicon oxidation produced two compounds which are in equilibrium: SiF$_4$(g) and SiF$_6^{2-}$ as proposed in Eq. (4):

$$\text{SiF}_4(g) = \text{SiF}_6^{2-} + 2\text{F}^-$$

As it is stated that fluoroacidity influences the cations coordination in the bath, Si(IV) ions have to be expressed as: SiF$_4$ + x$^-$. So Eq. (4) has to be amended, as written in Eq. (5):

$$\text{SiF}_4 + x\text{F}^- = \text{SiF}_6^{2-} + x\text{F}^-$$

According to the definition of fluoroacidity, the higher the F$^-$ concentration, the more basic the molten solution. So, the Si(IV) equilibrium study allows evaluating the fluoroacidity since a basic bath contributes to the silicon ions stabilization. Electrochemical techniques (cyclic and square wave voltammetries) were used in order to measure SiF$_4$ concentration vs. time. To correlate the

* Corresponding author. Tel.: +33 561556139; fax: +33 561556139. E-mail address: massot@chimie.ups-tlse.fr (L. Massot).

doi:10.1016/j.electacta.2011.03.099
peak current density of the Si ions reduction with their concentration, the Si(IV) electroreduction mechanism has to be known.

Studies on Si(IV) electroreduction have been reported by several authors [9–13]. The deposition mechanism of silicon from NaCl–KCl–K$_2$SiF$_6$, proposed by Delimarskii [9], involves a single reduction wave on a molybdenum electrode. Rao and Elwell [10] agreed that in LiF–NaF–KF, the K$_2$SiF$_6$ reduction in Si is a one step process with a charge transfer limitation. According to references [9,10], Si(IV) is reduced in a single step:

\[
\text{Si(IV)} + 4e^- = \text{Si} \quad (6)
\]

However, Chernov et al. [11] proposed that the silicon reduction proceeds in two stages on a platinum cathode in NaCl–KCl at 685 °C, which was confirmed by De Lepinay et al. [12] in LiF–KF and LiF–NaF–KF between 550 and 850 °C as:

\[
\begin{align*}
\text{Si(IV)} + 2e^- & = \text{Si(II)} \\ 
\text{Si(II)} + 2e^- & = \text{Si} 
\end{align*} \quad (7,8)
\]

Kuznetsova et al. [13] showed that a possible silicides formation before Si deposition, coming from a reaction between the electrode and the silicon, could explain the presence of a second wave found in the study of Chernov [11]. To avoid this phenomenon, a silver working electrode was preferred in our work since there is no Ag–Si intermetallic compounds [14]. The LiF–KF mixture was chosen to begin this study since many silicon electrodeposition studies in molten fluorides were carried out in this medium [12,15,16].

This paper is divided into two parts:

- The electroreduction process in order to conclude on the reduction pathway of the Si(IV) into Si.
- The kinetics of SiF$_4$ release in relation with the fluoroacidity of the melts.

The SiF$_4$ release rate was thus measured in several media (NaF–KF, LiF–KF, NaF–MgF$_2$, NaF–CaF$_2$, LiF–NaF, LiF, LiF–CaF$_2$) and a fluoroacidity scale is proposed.

2. Experimental

The cell was a vitreous carbon crucible placed in a cylindrical vessel made of refractory steel and closed by a stainless steel lid cooled by circulating water. This cell has been described in previous work [17]. The experiments were performed under an inert argon atmosphere (Linde). The cell was heated using a programmable furnace and the temperatures were measured using a chromel–alumel thermocouple.

2.1. Electrolyte

Several molten salts (Carlo Erba 99.995%) were used as electrolyte solvent: LiF–KF (51–49 mol%), LiF–NaF (60–40 mol%), NaF–KF (40–60 mol%), NaF–MgF$_2$ (78–22 mol%), NaF–CaF$_2$ (69–31 mol%), LiF–CaF$_2$ (80–20 mol%). All the solvent were initially dehydrated by heating under vacuum (7 × 10$^{-2}$ atm) from ambient temperature up to their melting point during one week. Silicon ions were introduced into the bath in the form of potassium or sodium hexafluorosilicate K$_2$SiF$_6$ or Na$_2$SiF$_6$ (Alfa Aesar 99.99%) powder.

2.2. Electrodes

Silver wires (1 mm diameter) were used as working electrode. The electrode surface area was determined after each experiment by measuring the wire immersion depth in the bath. The auxiliary electrode was a vitreous carbon (V25) rod (3 mm diameter) with a large surface area (2 cm$^2$). The potentials were measured with reference to a platinum wire (0.5 mm diameter) immersed in the molten electrolyte [18,19].

2.3. Electrochemical techniques

Cyclic voltammetry and square wave voltammetry were used for the investigation of the mechanism of Si(IV) ions reduction. All the electrochemical studies were performed with an Autolab PGStat 30 potentiostat/galvanostat controlled by a computer using the research software GPES.
3. Results and discussion

3.1. Si(IV) reduction mechanism

3.1.1. Cyclic voltammetry

Cyclic voltammetry was carried out on a silver electrode in LiF–KF–K$_2$SiF$_6$ system in the 700–900°C temperature range. Fig. 1 presents a typical cyclic voltammogram of the LiF–KF–K$_2$SiF$_6$ (0.35 mol kg$^{-1}$) system at 800°C on silver electrode. This cyclic voltammogram exhibits only one reduction peak at $-0.9$ V vs. Pt and its associated reoxidation peak at $-0.65$ V vs. Pt. The asymmetrical shape of the reoxidation peak is typical of the redissolution of a solid phase deposited during the cathodic run (stripping peak). The linear relationship between Si(IV) reduction peak intensity and the square root of the scan rate has been verified in the inset of Fig. 1, proving that the electrochemical reduction process is controlled by the Si(IV) ions diffusion in the bath (Berzins Delahay [20] valid for a reversible soluble/insoluble system):

$$I_p = -0.61 \, nFSc_0 \left( \frac{nFD}{RT} \right)^{1/2} V^{1/2}$$

where $n$ is the number of exchanged electrons, $F$ is the Faraday’s constant (C mol$^{-1}$), $S$ is the electrode surface area (cm$^2$), $c_0$ is the solute concentration (mol cm$^{-3}$), $D$ is the diffusion coefficient (cm$^2$ s$^{-1}$), $T$ is the temperature (K) and $V$ is the potential scan rate (V s$^{-1}$).

The Si(IV) concentration in the bath was measured by sampling the bath after each Si(IV) additions and dissolution in acidic media, using Inductively Coupled Plasma-Atomic Emission Spectroscopy (ICP-AES). A linear relationship between the cathodic peak intensity and the silicon ions concentration has been plotted in Fig. 2, confirming that the cathodic peak can be attributed to the Si(IV) ions reduction into Si. The relation between peak intensity and silicon concentration gives at 800°C:

$$j_p = -2.14 \, [\text{Si(IV)}]$$

Using Eq. (10) and the slope of Fig. 1 inset, the diffusion coefficient value is $(4.7 \pm 0.2) \times 10^{-6}$ cm$^2$ s$^{-1}$ in LiF–KF–K$_2$SiF$_6$ at 800°C. Kuznetsova found a Si(IV) ions diffusion coefficient equal to $(1.64 \pm 0.25) \times 10^{-5}$ cm$^2$ s$^{-1}$ at 750°C in a NaCl (43.25 mol%)–KCl (43.25 mol%)–NaF (13.50 mol%)–K$_2$SiF$_6$ mixture [13]. The difference between the values can be explained by the temperature and medium effects, which imply a fluoroacidity difference.

![Fig. 2. Linear relationship between reduction peak current density and Si(IV) concentration in the bath measured by ICP; Working electrode: Ag; Auxiliary el.: vitreous carbon; Reference el.: Pt; Scan rate = 100 mV s$^{-1}$; $t = 800$ °C.](image2)

![Fig. 3. Square wave voltammogram of the LiF–KF–K$_2$SiF$_6$ (14.2 \times 10^{-2}$ mol kg$^{-1}$); Working electrode: Ag (surface area = 0.31 cm$^2$); Auxiliary el.: vitreous carbon; Reference el.: Pt; Frequency = 9 Hz; $t = 800$ °C / Inset: Linear relationship of Si(IV) reduction peak current density vs. the square root of the scanning potential rate.](image3)
3.1.2. Square wave voltammetry

The square wave voltammetry was used to confirm the number of exchanged electrons of Si(IV) reduction, as the half-width of a peak is linked to the number of exchanged electrons [21]:

\[ W_{1/2} = 3.52 \frac{RT}{nF} \]  

where \( W_{1/2} \) represents the half-width of a peak (V).

Fig. 3 shows a square wave voltammogram of the LiF–KF–K$_2$SiF$_6$ (0.57 mol kg$^{-1}$) system on a silver electrode at 800 °C at 9 Hz. The shape is an asymmetrical Gaussian curve, characteristic of a soluble/insoluble system [22,23]. The Eq. (11) is valid if the peak current density is linear with the square root of the frequency [24], which is verified in the inset of Fig. 3. The peak dissymmetry is due to the currentless nucleation overvoltage, associated with formation of the solid phase on the electrode, which delays the current growth [25,26]. The deconvolution of the experimental signal allows finding the number of electrons using the semi half-width in the part of the voltammogram unaffected by the nucleation phenomenon [22]. The calculation of the number of exchanged electrons gives \( n = 3.9 \pm 0.1 \). These results allow concluding that the silicon reduction in molten salts is a one-step process exchanging four electrons as mentioned in Eq. (6).

3.2. Kinetics of SiF$_4$(g) release

According to the Eq. (5), the SiF$_4$(g) release leads to a Si(IV) peak intensity decrease. Consequently, this reaction was used to compare the fluoroacidity of the molten fluorides, as the free F$^-$ content in the bath acts on the equilibrium constant and thus on the kinetic rate of SiF$_4$(g) release. To study the kinetics of SiF$_4$(g) release in the mixture, the variation of the Si(IV) ions concentration was plotted vs. time after an addition of K$_2$SiF$_6$ (0.57 mol kg$^{-1}$) in LiF–KF at 800 °C. In Fig. 4, the plot is divided into two parts.

The first part of the curve where the peak current density increases corresponds to the K$_2$SiF$_6$ dissolution in the bath, up to a maximum value depending on the nature of the bath and the temperature. The K$_2$SiF$_6$ dissolution time was shorter than the evaporation rate of silicon species. Then, the silicon current density decreases due to the reaction described in Eq. (5). The second part has a logarithm shape likely corresponding to a first order kinetic. By plotting the logarithm of the Si(IV) concentration vs. time as expected is a straight line, according to the Eq. (12), shown in Fig. 5, demonstrating that the equilibrium reaction kinetics is a first order one.

The measurement of the Si(IV) concentration allows the kinetic rate of SiF$_4$(g) release (first order) to be calculated:

\[ v = - \frac{d[Si(IV)]}{dt} = k[Si(IV)] \]  

where \( k \) is the kinetic constant (s$^{-1}$), [Si(IV)] is the dissolved silicon concentration (mol kg$^{-1}$) and \( v \) is rate reaction (mol kg$^{-1}$ s$^{-1}$).

The determination of \( k \) is a classical methodology of first order kinetics:

\[ \ln[Si(IV)] = -kt + \text{constant} \]  

Plotting \( \ln[Si(IV)] \) vs. time leads to the value of the rate constant \( k \) of SiF$_4$(g) release. According to the slope of the curve, the rate constant value is 19 \( \times \) 10$^{-7}$ s$^{-1}$ at 800 °C. The plotting of \( \ln[Si(IV)] \) vs. time at other temperatures allows calculating \( k \) at these temperatures; the obtained values should obey the Arrhenius’ law:

\[ k = A \exp \left( \frac{-E_a}{RT} \right) \]  

where \( E_a \) is the activation energy (J mol$^{-1}$) and \( A \) the pre-exponential factor (s$^{-1}$).

This assumption has been verified in Fig. 6 where the plot of the rate constant logarithm vs. the inverse of temperature is linear with a slope correlated to the activation energy. For LiF–KF eutectic, the activation energy is found to be around 213 kJ mol$^{-1}$ and the pre-exponential factor 47 \( \times \) 10$^3$ s$^{-1}$.

This rate constant is correlated to the fluoroacidity of each bath and allows sorting different mixtures fluoroacidity. A low rate constant means that the silicon ions remain in the bath. Consequently, the apparent stability of these ions is favored and, according to Eq. (5), the salt mixture is assumed to be basic. In the next paragraph,

Fig. 5. Linear relationship of the logarithm of the Si(IV) concentration in the bath vs. time; \( t = 800 ^\circ \text{C} \).
the operating conditions comparison is presented, concerning the salt composition and the mixture choice.

3.3. Comparison of operating conditions

3.3.1. Influence of LiF–KF composition

The values of the kinetic constant of reaction (5) are gathered in Fig. 7 for several compositions of LiF–KF (0, 20, 40, 49 (eut.), 60, 80 mol%). The medium composition influence was studied for a LiF–KF mixture because it can include the study of pure LiF due to its low vapour pressure, whereas pure KF and NaF cannot be experimented due to a too high vapour pressure for KF and a too high melting point for NaF (996 °C). Fig. 7 presents the SiF₄(g) release rate constants determined at a temperature of 900 °C for each studied media. We observe that, when the KF content increases, the rate constant value decreases, meaning that the mixture tends to be more and more basic. It can be concluded that KF is more basic than LiF. Concerning the 51 mol% LiF-49 mol% KF composition, the rate constant is lower than expected from the variation of k for other compositions, meaning that the bath is stable. Notice that the lowest value of rate constant was found for the LiF-KF (20-80 mol%). For this mixture (tₑ = 759 °C), a high volatility is observed at high temperature. To avoid this phenomenon, the second lowest value of rate constant was chosen, corresponding for a salt mixture, to the eutectic composition. The results concerning the rate constant of eutectic mixture of other binary fluoride systems are presented and discussed in the next paragraph.

3.3.2. Influence of binary mixtures

The values of k for other fluoride media are gathered in Table 1. The precision of rate constants is comprised between 2% for basic baths (high KF content) and 8% for more acidic ones, due to shorter experiment duration. The results are presented for eutectic compositions salts: the left part is composed of monovalent salts whereas in the right part the mixtures are composed of one monovalent and one divalent ion. The comparison of the fluoroacidity of these mixtures was done at the same temperature of 900 °C. Thanks to Eq. (14), the temperature dependence of k is known, thus allowing different mixtures to be compared. Indeed, a too high difference between the melting point and the experimental temperature is not suitable for avoiding the salt distillation (about 250 °C).

<table>
<thead>
<tr>
<th>Temperature (°C)</th>
<th>LiF</th>
<th>NaF–KF (mol%)</th>
<th>LiF–KF (mol%)</th>
<th>LiF–NaF (mol%)</th>
<th>NaF–MgF₂ (mol%)</th>
<th>NaF–CaF₂ (mol%)</th>
<th>LiF–CaF₂ (mol%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>700</td>
<td>848</td>
<td>718</td>
<td>492</td>
<td>652</td>
<td>835</td>
<td>814</td>
<td>760</td>
</tr>
<tr>
<td>750</td>
<td></td>
<td>12.3</td>
<td>178</td>
<td>241</td>
<td>243</td>
<td>241</td>
<td></td>
</tr>
<tr>
<td>800</td>
<td></td>
<td>12.3</td>
<td>178</td>
<td>241</td>
<td>243</td>
<td>241</td>
<td></td>
</tr>
<tr>
<td>850</td>
<td></td>
<td>12.3</td>
<td>178</td>
<td>241</td>
<td>243</td>
<td>241</td>
<td></td>
</tr>
<tr>
<td>900</td>
<td></td>
<td>12.3</td>
<td>178</td>
<td>241</td>
<td>243</td>
<td>241</td>
<td></td>
</tr>
<tr>
<td>950</td>
<td></td>
<td>12.3</td>
<td>178</td>
<td>241</td>
<td>243</td>
<td>241</td>
<td></td>
</tr>
</tbody>
</table>

Table 1

Rate constant of Si(IV) ions release (k) for different fluoride media at different temperature; italic values calculating with Eq. (14).
The Si(IV) rate constant is the lowest for NaF–KF meaning that it is the most basic bath. All the results are gathered on Fig. 8 in a qualitative scale representing mixtures from the most basic bath to the most acidic one.

The left side of Table 1 demonstrates the role of KF in the basicity of the melts: for example, KF–NaF (60–40 mol%) is more basic than LiF–NaF (60–40 mol%), while the NaF content is identical in each mixture; thus the difference of fluoroacidity is influenced by the counter-ion: KF is more basic than LiF. Likewise LiF–KF is more basic than LiF–NaF while the composition in LiF is similar, that means that KF is more basic than NaF. Moreover if we compare NaF–KF and LiF–KF, NaF is more basic than LiF. Hence for monovalent ions, we can assume that the fluoroacidity scale is KF < NaF < LiF. The experiments with divalent ions are more difficult to interpret because the compositions of divalent compounds are too different. Nevertheless, the LiF and LiF–CaF$_2$ comparison allows concluding that CaF$_2$ is more acidic than LiF.

### 4. Conclusion

The equilibrium between Si(IV) ions and SiF$_4$(g) in molten fluorides is highly influenced by the solvent cations. In cyclic voltammograms, the Si(IV) reduction peak intensity decreases vs. time. So, kinetics of SiF$_4$(g) release depends on the bath fluoroacidity, since a bath containing a high free F$^-$ ions concentration contributes to stabilizing silicon ions in the medium. Using these reaction kinetics results, the following scale of fluoroacidity was established from most basic to most acidic: NaF–KF < LiF–KF < NaF–MgF$_2$ < NaF–CaF$_2$ < LiF–NaF < LiF–LiF–CaF$_2$. The comparison of the acidity of these mixtures proved that the most basic compounds are monovalents as KF < NaF < LiF. A higher valency of divalent compounds favours an acidic behaviour but the comparison between CaF$_2$ and MgF$_2$ is experimentally difficult to perform. For acidic baths, the k value is hard to determine due to the uncertainty of experimental data. To confirm these results and for a better acid baths fluoroacidity evaluation, a similar system with a species in equilibrium with a gaseous compound should be studied. Finally a perspective of this work will be the achievement of a quantitative fluoroacidity scale.

### Acknowledgements

The authors express their thanks to the Research National Agency ANR-09-BLAN-0188 for their financial support for this research.

### References